



JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

SOT-89 Plastic-Encapsulate Transistors

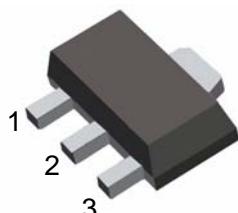
2SD1119 TRANSISTOR (NPN)

FEATURES

- Low collector-emitter saturation voltage $V_{CE(sat)}$
- Satisfactory operation performances at high efficiency with the low voltage power supply.

SOT-89

1. BASE
2. COLLECTOR
3. Emitter



MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Value | Units |
|-----------|-------------------------------|---------|------------------|
| V_{CBO} | Collector-Base Voltage | 40 | V |
| V_{CEO} | Collector-Emitter Voltage | 25 | V |
| V_{EBO} | Emitter-Base Voltage | 7 | V |
| I_c | Collector Current -Continuous | 3 | A |
| P_c | Collector Dissipation | 500 | mW |
| T_J | Junction Temperature | 150 | $^\circ\text{C}$ |
| T_{stg} | Storage Temperature | -55-150 | $^\circ\text{C}$ |

ELECTRICAL CHARACTERISTICS ($T_{amb}=25^\circ\text{C}$ unless otherwise specified)

| Parameter | Symbol | Test conditions | MIN | TYP | MAX | UNIT |
|--------------------------------------|---------------|--|-----|-----|-----|---------------|
| Collector-base breakdown voltage | $V_{(BR)CBO}$ | $I_C=100\mu\text{A}, I_E=0$ | 40 | | | V |
| Collector-emitter breakdown voltage | $V_{(BR)CEO}$ | $I_C=1\text{mA}, I_B=0$ | 25 | | | V |
| Emitter-base breakdown voltage | $V_{(BR)EBO}$ | $I_E=10\mu\text{A}, I_C=0$ | 7 | | | V |
| Collector cut-off current | I_{CBO} | $V_{CB}=10\text{V}, I_E=0$ | | | 0.1 | μA |
| Emitter cut-off current | I_{EBO} | $V_{EB}=6\text{V}, I_C=0$ | | | 0.1 | μA |
| DC current gain | $h_{FE(1)}$ | $V_{CE}=2\text{V}, I_C=500\text{mA}$ | 230 | | 600 | |
| | $h_{FE(2)}$ | $V_{CE}=2\text{V}, I_C=2\text{A}$ | 150 | | | |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_C=3\text{A}, I_B=0.1\text{A}$ | | | 1 | V |
| Transition frequency | f_T | $V_{CE}=6\text{V}, I_C=50\text{mA}, f=200\text{MHz}$ | | 150 | | MHz |
| Collector output capacitance | C_{ob} | $V_{CB}=20\text{V}, f=1\text{MHz}$ | | | 50 | pF |

CLASSIFICATION OF $h_{FE(1)}$

| Rank | Q | R |
|---------|---------|---------|
| Range | 230-380 | 340-600 |
| Marking | TQ | TR |

Typical Characteristics

2SD1119

